

| BV_{DSX}/BV_{DGX} | $R_{DS(ON)}$ (max) | I_{DSS} (min) | Package |
|---------------------|--------------------|-----------------|---------|
| 250V | 4.0Ω | 300mA | SOT-89 |

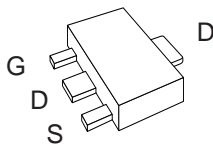
Features

- Depletion mode device offers low $R_{DS(ON)}$ at cold temperatures
- Low on resistance 4 ohms max. at 25°C
- High input impedance
- High breakdown voltage 250V
- Low $V_{GS(off)}$ voltage -1.6 to -3.9V
- Small package size SOT-89

Applications

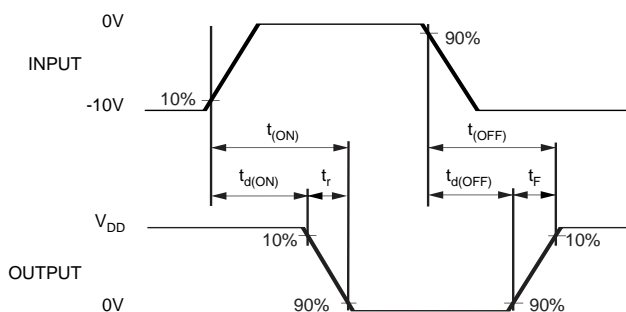
- Ignition modules
- Normally-on switches
- Solid state relays
- Converters
- Telecommunications
- Power supply

Package Pinout



(SOT-89)

Switching Waveforms and Test Circuit



Description

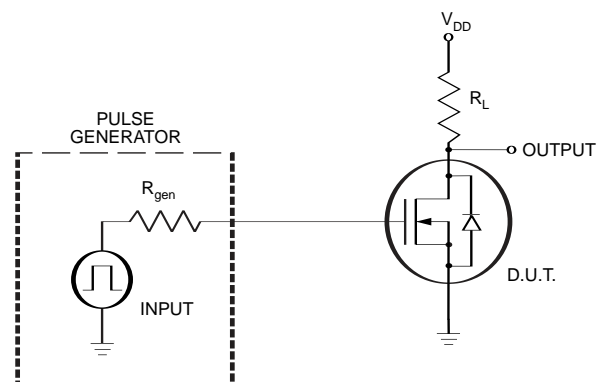
The CPC3703C is an N-channel depletion mode field effect transistor (FET) that utilizes Clare's proprietary third generation vertical DMOS process. Third generation process realizes world class, high voltage MOSFET performance in an economical silicon gate process. Our vertical DMOS process yields a robust device for high power applications with high input impedance. The CPC3703C is a highly reliable FET device that has been used extensively in Clare's solid state relays for industrial and telecommunications applications.

This device excels in power applications requiring low drain-source resistance, particularly in cold environments such as automotive ignition modules. The CPC3703C offers a low 4 ohm maximum on-state resistance at 25°C.

The CPC3703C has a minimum breakdown voltage of 250V and is available in an SOT-89 package. As with all MOS devices, the FET structure prevents thermal runaway and thermal-induced secondary breakdown.

Ordering Information

| Part # | Description |
|------------|--------------------|
| CPC3703C | SOT-89 (100/Tube) |
| CPC3703CTR | SOT-89 (2000/Reel) |



Absolute Maximum Ratings

| Parameter | Ratings | Units |
|---|-------------|-------|
| Drain-to-Source Voltage | 250 | V |
| Gate-to-Source Voltage | ±20 | V |
| Total Package Dissipation | 1.6 | W |
| Operational Temperature | -55 to +125 | °C |
| Storage Temperature | -55 to +125 | °C |
| Soldering Temperature (10 seconds Max) | +220 | °C |

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

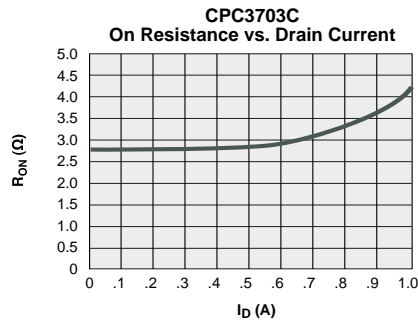
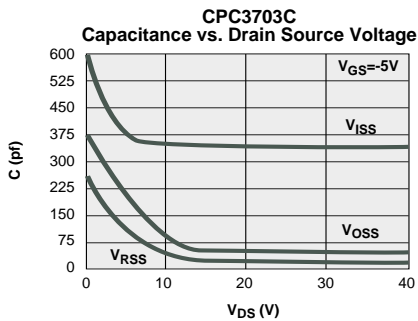
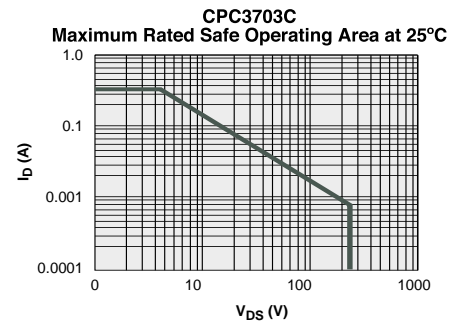
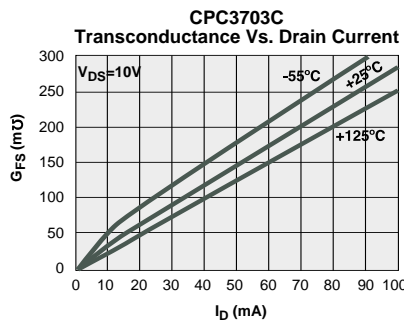
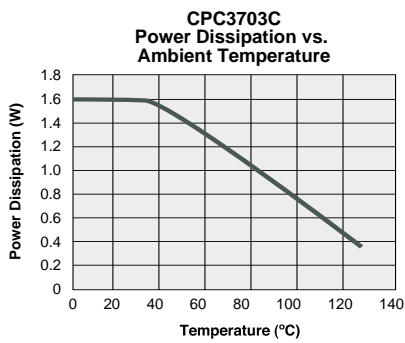
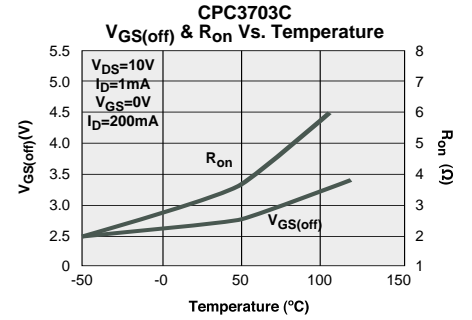
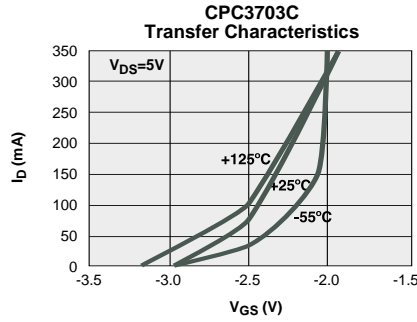
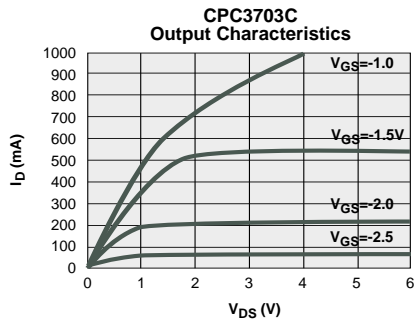
Thermal Characteristics

| Package | I _D (continuous) | I _D (pulsed) | Power Dissipation @TA=25°C | θ _{jc} °C/W | I _{DR} | I _{DRM} |
|---------|-----------------------------|-------------------------|-------------------------------|-------------------------|-----------------|------------------|
| SOT-89 | 360mA | 600mA | 1.6W | 15 | 360mA | 600mA |

Electrical Characteristics (@25°C unless otherwise specified)

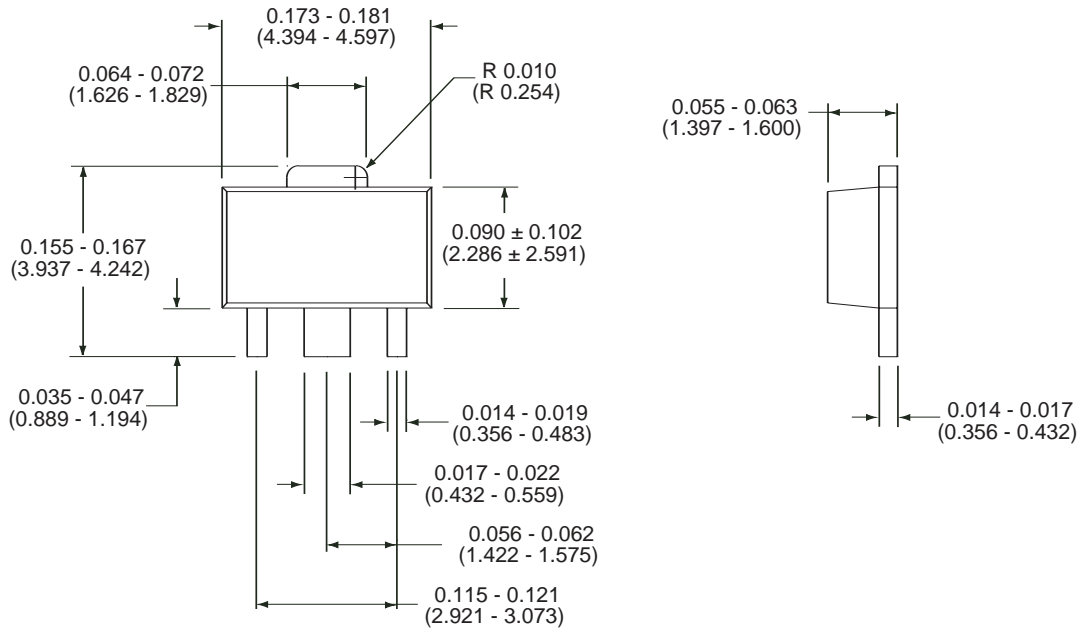
| Parameter | Symbol | Conditions | Min | Typ | Max | Units |
|--|---------------------------|--|------|-----|------|-------|
| Drain-to-Source Breakdown Voltage | BV _{DSX} | V _{GS} = -5.0V, I _D =100μA | 250 | - | - | V |
| Gate-to-Source Off Voltage | V _{GS(off)} | I _{DS} = 15V, I _D =1.0mA | -1.6 | - | -3.9 | V |
| Change in V _{GS(off)} with Temperatures | $\frac{dV_{GS(off)}}{dT}$ | V _{DS} = 15V, I _D =1.0mA | - | - | 4.5 | mV/°C |
| Gate Body Leakage Current | I _{GSS} | V _{GS} =±20V, V _{DS} =0V | - | - | 100 | nA |
| Drain-to-Source Leakage Current | I _{D(off)} | V _{GS} = -5V, V _{DS} =Max Rating | - | - | 1 | μA |
| | | V _{GS} = -5V, V _{DS} =0.8 Max Rating T _A =125°C | - | - | 1 | mA |
| Saturated Drain-to-Source Current | I _{DSS} | V _{GS} = 0V, V _{DS} =15V | 300 | - | - | mA |
| Static Drain-to-Source ON-State Resistance | R _{DS(on)} | V _{GS} = 0V, I _D =200mA | - | - | 4.0 | Ω |
| Change in R _{DS(on)} with Temperatures | $\frac{dR_{DS(on)}}{dT}$ | V _{GS} = 0V, I _D =200mA | - | - | 1.1 | %/°C |
| Forward Transconductance | G _{FS} | I _D = 100mA, V _{DS} = 10V | 225 | - | - | mS |
| Input Capacitance | C _{ISS} | V _{GS} = -5V | - | 327 | 350 | pF |
| Common Source Output Capacitance | C _{OSS} | V _{DS} = 25V | - | 51 | 65 | |
| Reverse Transfer Capacitance | C _{RSS} | f= 1.0Mhz | - | 27 | 35 | |
| Turn-ON Delay Time | t _{d(on)} | V _{DD} = 25V | - | 23 | 35 | ns |
| Rise Time | t _r | I _D = 150mA | - | 8 | 20 | |
| Turn-OFF Delay Time | t _{d(off)} | V _{GS} = 0V to -10V | - | 17 | 25 | |
| Fall time | t _f | R _{GEN} = 50Ω | - | 70 | 80 | |
| Source-Drain Diode Voltage Drop | V _{SD} | V _{GS} = -5.0V, I _{SD} = 150mA | - | 0.6 | 1.8 | V |

PERFORMANCE DATA*



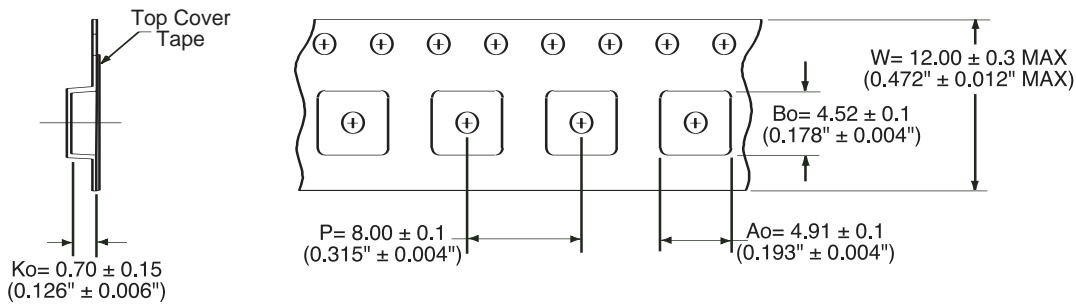
*The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

MECHANICAL DIMENSIONS



Dimensions
inches
(mm)

Tape and Reel Information



Dimensions
mm
(inches)

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